CTLSH1-40M832D

SURFACE MOUNT DUAL, HIGH CURRENT, LOW V_F SILICON SCHOTTKY DIODES



TEMOJED OAG

MARKING CODE: CFA



DESCRIPTION:

The CENTRAL SEMICONDUCTOR

CTLSH1-40M832D Dual, Isolated, Low V_F Schottky diodes are designed for applications where small size and operational effciency are the prime requirements. With a maximum power dissipation of 1.65W, and a very small package footprint (approximately equal to the SOT-23), this leadless package design is capable of dissipating up to 4 times the power of similar devices in comparable sized surface mount packages.

FEATURES:

- Dual Chip Device
- High Current (I_F=1.0A)
- Low Forward Voltage Drop (V_F=0.55V MAX @ 1.0A)

APPLICATIONS:

- DC/DC Converters
- Reverse Battery Protection
- Battery Powered Portable
 Equipment

High Thermal Efficiency

Small TLM 3x2mm case

MAXIMUM RATINGS: $(T_{\Delta}=25^{\circ}C)$							
	SYMBOL		UNITS				
Peak Repetitive Reverse Voltage	V _{RRM}	40	V				
Continuous Forward Current	١ _F	1.0	А				
Peak Repetitive Forward Current, tp \leq 1ms	I _{FRM}	3.5	А				
Forward Surge Current, tp=8ms	IFSM	10	А				
Power Dissipation	PD	1.65	W*				
Operating and Storage							
Junction Temperature	т _Ј , т _{stg}	-65 to +150	°C				
Thermal Resistance	Θ_{JA}	75.8	°C/W*				

ELECTRICAL CHARACTERISTICS: (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
I _R	V _R = 5V			10	μA
I _R	V _R = 8V			20	μΑ
I _R	V _R = 15V			50	μA
вv _R	I _R = 100μA	40			V
V _F	I _F = 10mA			0.29	V
V _F	I _F = 100mA			0.36	V
V _F	I _F = 500mA			0.45	V
V _F	I _F = 1.0A			0.55	V
CJ	V _R = 4.0V, f=1.0MHz		50		pF

*FR-4 Epoxy PCB with copper mounting pad area of 54mm²

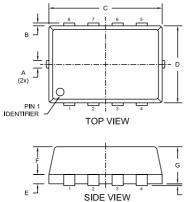
R2 (27-April 2006)

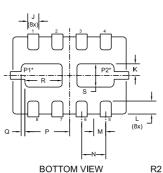


CTLSH1-40M832D

SURFACE MOUNT DUAL, HIGH CURRENT, LOW V_F SILICON SCHOTTKY DIODES

TLM832D CASE - MECHANICAL OUTLINE

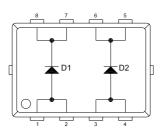




* Note:

- Exposed pad P1 common to pins 7 and 8

- Exposed pad P2 common to pins 5 and 6

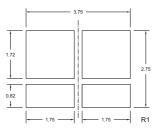


LEAD CODE:
 1) ANODE D1
 2) ANODE D1
 3) ANODE D2
 4) ANODE D2
 4) ANODE D2
 5) CATHODE D2
 6) CATHODE D2
 7) CATHODE D1
 8) CATHODE D1

MARKING CODE: CFA

DIMENSION MILLIMETERS INCHES SYMBC MIN MAX MIN MAX А 0.007 0.012 0.170 0.300 0.00 0.125 0.114 2.900 C 0.122 3.100 0.08 1.900 0.075 2.100 D 0.006 0.010 0.150 0.250 0.026 0.03 0.650 G 0.031 0.039 0.800 1.000 Н 0.000 0.00 0.000 0.050 0.009 0.013 0.240 0.340 J 0.006 0.01 0.160 L 0.008 0.018 0.200 0.450 М N 0.026 0.650 0.040 0.048 1.010 1.210 Р Q 0.004 0.100 R 0.032 1.020 0.430 0.630 TLM832D (REV: R2) 0.017 0.0

> Suggested mounting pad layout for maximum power dissipation (Dimensions in mm)



For standard mounting refer to TLM832D Package Details

R2 (27-April 2006)